

TOSHIBA Bi-CMOS INTEGRATED CIRCUIT SILICON MONOLITHIC

T B 3 1 2 2 4 F

RF 1CHIP IC FOR 46 / 49MHz CORDLESS TELEPHONE

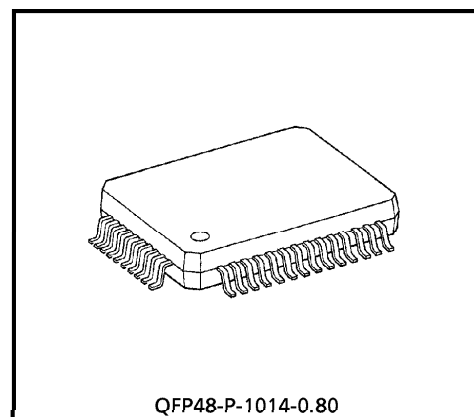
One packaging three systems PLL, IF detector, Comander.

It is possible to reduce many external parts. This IC is suitable for cordless telephone base set, hand set radio section.

FEATURES

- Low operating voltage $V_{CC} = 2.0 \sim 6.0V$
- PLL operating frequency $\sim 60MHz$
- Serial control for all status
- Built-in 1st Mixer : Operating frequency $\sim 60MHz$
- Built-in RECEIVER AMP
- Battery-Saving function for intermittent receiving
- Variable BATTERY ALARM (5 threshold setting)
- Extremely low consumption current
 - $I_{CC} = 50\mu A$ (Typ.) at battery-saving
 - $I_{CC} = 7.5mA$ (Typ.) at stand-by
 - $I_{CC} = 12.5mA$ (Typ.) communication
- Regulator for RX front end : 2.0V
- High speed and stable CH search system by combination of NOISE DETECTION and RSSI
- Small Package

QFP 48Pin (0.8mm pitch)



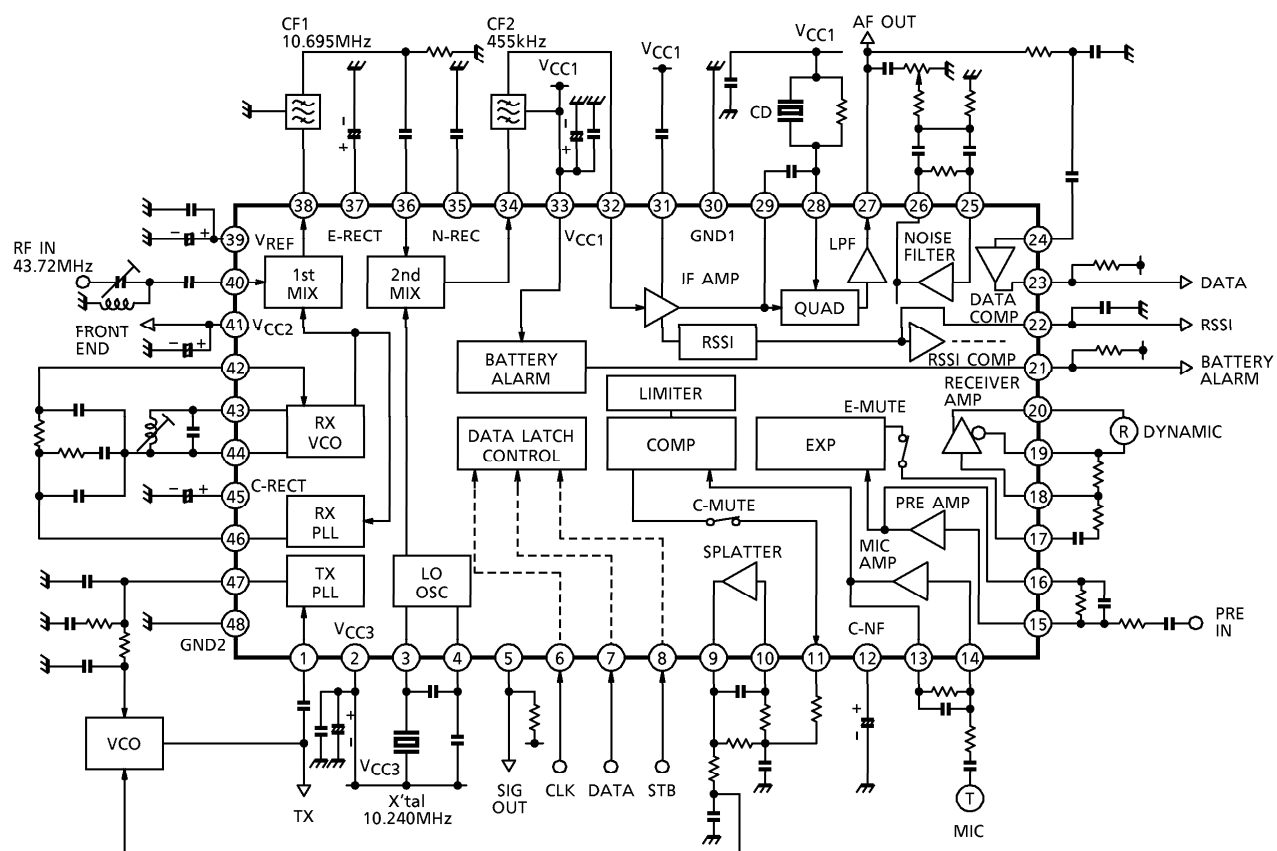
Weight : 0.83g (Typ.)

Handle with care to prevent devices from deterioration by static electricity.

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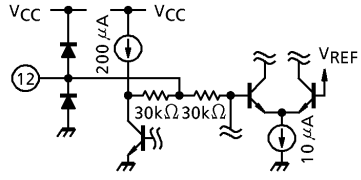
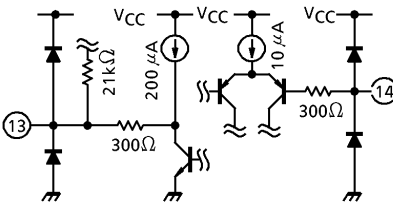
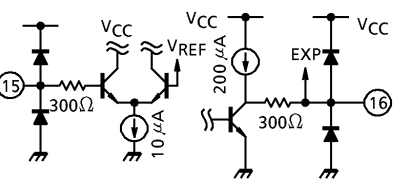
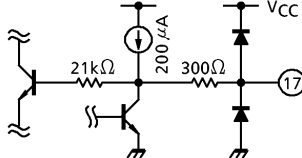
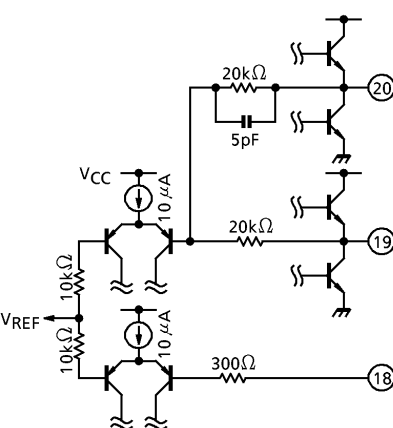
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BLOCK DIAGRAM



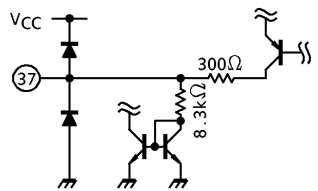
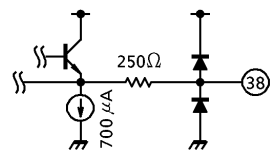
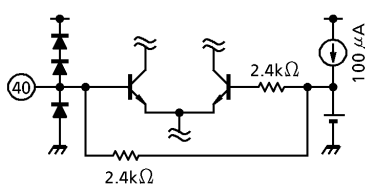
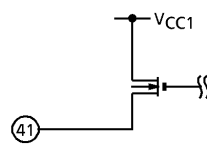
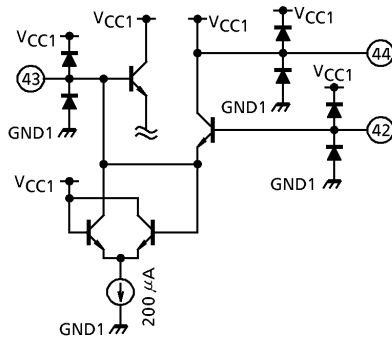
PIN FUNCTION (The values of resistor and capacitor are typical.)

PIN No.	PIN NAME	FUNCTION	INTERNAL EQUIVALENT CIRCUIT
1	TX-IN	Input terminal of TX-VCO oscillation signal.	
2	VCC3	Power supply terminal.	—
3	LO-1	LOCAL OSCILLATOR input and output terminals. Colpitts oscillator is formed by internal emitter follower and external X'tal. And external injection is possible from pin 3.	
4	LO-2		
5	SIG OUT	Output terminal of detection signal. It is the open drain output.	
6	CLK	Input terminal of clock.	
7	DATA	Input terminal of serial data.	
8	STB	Input terminal of strobe signal.	
9	FIL-OUT	Output of FILTER AMP.	
10	FIL-IN	Input of FILTER AMP.	
11	COMP-OUT	Output of COMPRESSOR.	

PIN No.	PIN NAME	FUNCTION	INTERNAL EQUIVALENT CIRCUIT
12	C-NF	Feedback circuit of T type is formed by external capacitor with SUM AMP.	
13	MIC-OUT	Output of MIC AMP and connected directly to input of SUM AMP.	
14	MIC-IN	Input terminal of MIC AMP.	
15	PRE-IN	Inverted input of PRE AMP.	
16	PRE-OUT	Output of PRE AMP. Connected directly to EXPANDER.	
17	EXP-OUT	Output of SUM AMP at EXPANDER. The signal from gain cell is gained by inverted amp.	
18	RECE-IN	Inverted input of RECEIVER AMP.	
19	RO1	Receiving output for a dynamic receiver. Used for BTL output type, RO1 terminal and RO2 terminal.	
20	RO2		

PIN No.	PIN NAME	FUNCTION	INTERNAL EQUIVALENT CIRCUIT
21	BAT-ALM	BATTERY ALARM terminals. When V_{CC} decrease V_{BAT-L} , This terminal outputs "H" level. Detection voltage is controled by data bit. This terminal is open collector output.	
22	RSSI	This terminal outputs DC level according to input signal level to IF AMP. Dynamic range is around 70dB.	
23	DATA-OUT	Output terminal for wave form shaping. This terminal is open collector output.	
24	D-COMP-IN	DATA COMPARATOR input terminal. This terminal input demodulation signal of DATA.	
25	N FIL-IN	NOISE FILTER input and output terminals. BPF is composed of external capacitors and resistors. Connected internally to rectifier circuit by coupling capacitor.	
26	N FIL-OUT		
27	AF-OUT	Demodulated signal output terminal. Carrier leak is small as LPF is built-in. Output impedance is around 360Ω.	
28	QUAD	Phase shift signal input terminal of FM demodulator.	

PIN No.	PIN NAME	FUNCTION	INTERNAL EQUIVALENT CIRCUIT
29	IF-OUT	Output terminal of IF AMP.	
30	GND1	GND terminal.	—
31	DEC	2nd IF input and decoupling for bias. Input impedance is around 1.5kΩ.	
32	IF-IN		
33	V _{CC1}	Power supply terminal.	—
34	2nd MIX-OUT	MIX output terminal. Output impedance is around 1.5kΩ.	
35	N-REC	After output of NOISE FILTER amplified around 20dB, noise signal is rectified by external capacitor.	
36	2nd MIX-IN	1st IF signal input terminal. Input impedance is around 4.7kΩ at 10.695MHz.	

PIN No.	PIN NAME	FUNCTION	INTERNAL EQUIVALENT CIRCUIT	
37	E-RECT	Connected capacitor for full-wave rectifier circuit of EXPANDER.		
38	1st MIX-OUT	MIX output terminal. Externally connects filters. Output impedance is 330Ω (Typ.)		
39	V REF	Reference terminal through internal buffer of compander block.	—	
40	1st MIX-IN	MIX input terminal. Double-balance MIX.		
41	VCC2	Regulator terminal. Output voltage is 2.0V.		
42	VCO-CONT	Voltage control terminal of RX-VCO.		
43	VCO-1	They are resonance terminals of RX-VCO.		
44	VCO-2			
45	C-RECT	Terminal for rectifier of COMPRESSOR. Almost the same circuit as E-RECT terminal.	—	

PIN No.	PIN NAME	FUNCTION	INTERNAL EQUIVALENT CIRCUIT
46	RX-OUT	Output terminal of CHARGE PUMP. CHARGE PUMP is constant current output circuit, and output current is varied by input serial data.	
47	TX-OUT		
48	GND2	GND terminal.	—

1. General description

TB31224F is controlled by serial parts pin 6, 7, 8, and makes all situations by these serial bits for RF part in 46/49MHz cordless telephone such as intermittent receiving state.

Not only 46/49MHz cordless telephone but CT0 cordless phone that has frequency spec. between about 20MHz and 60MHz can be also set up TB31224F.

POWER SUPPLY BLOCK ASSIGN

V _{CC1}	GND1	1st MIX, 2nd MIX, IF AMP, QUAD, NOISE DET, RX-VCO, V _{CC2} , DATA COMP, COMPANDER, RECEIVER AMP, SPLATTER
V _{CC3}	GND2	RX-PLL, TX-PLL, LO OSC, DATA LATCH CONTROL

Fig.1 shows power supply connections for each terminal, V_{CC1} , V_{CC3} is directly connected to battery.

In case of base set battery might be replaced with 5V regulator.

V_{CC1} and V_{CC3} are not joined internally.

(Note) Bypass capacitors at V_{CC1} , V_{CC2} , V_{CC3} should be layoutted very close to each terminal and enough appropriate capacitance value and kind of capacitor for frequency should be applied.

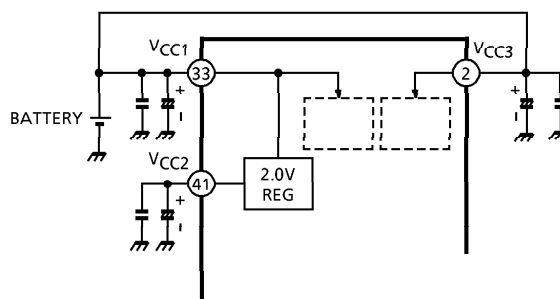


Fig.1

2. PLL

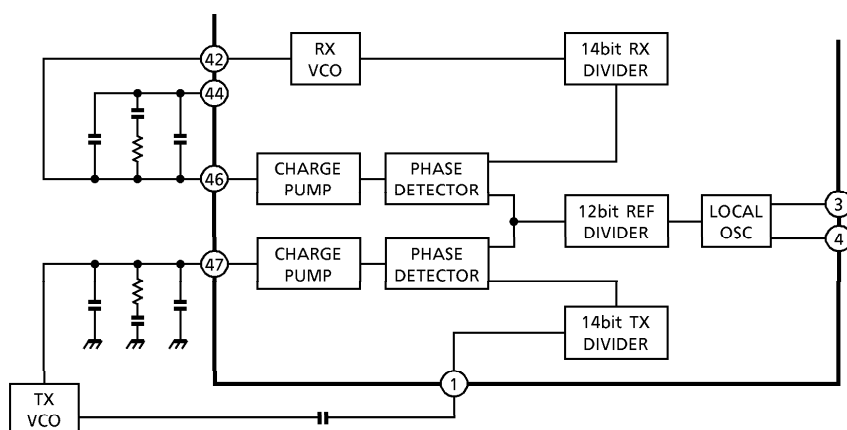


Fig.2

PLL counting number in RX DIVIDER, TX DIVIDER and REF DIVIDER are all programmable by serial data control.

CHARGE PUMP doesn't have voltage output but current output, therefore loop gain can show good linearity and external resister can be reduced. (Fig.3)

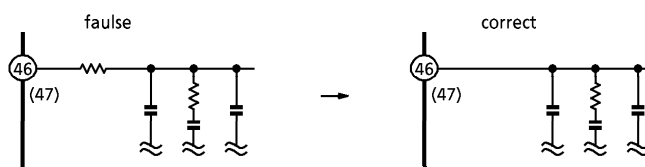


Fig.3

3. Data latch control

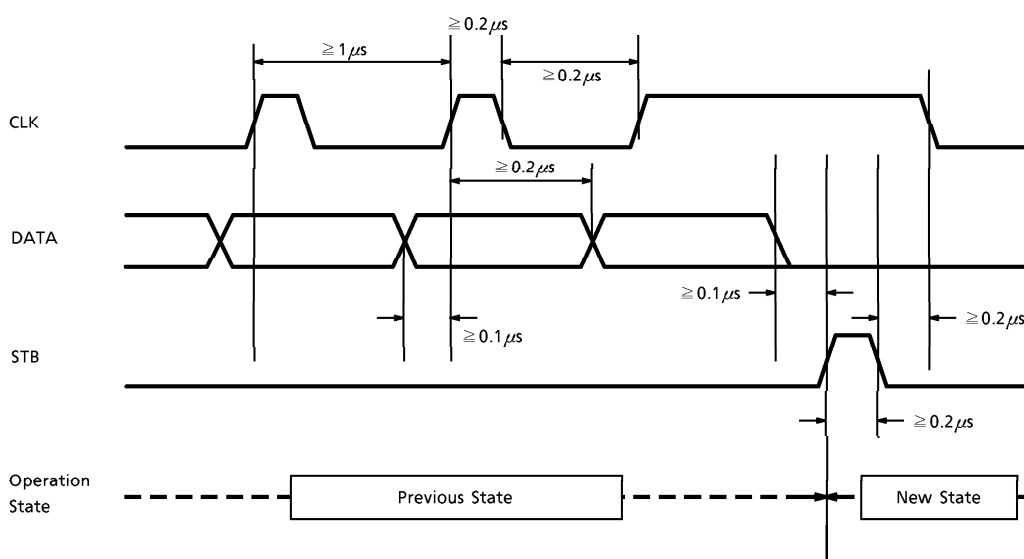
This block has 4 registers assigned by 2 bits CODE. DATA is read on the time of up edge of CLK. When STB receives high signal, DATA in shift register is sent into LATCH to control block which CODE indicates and the operation starts.

CODE ASSIGN

CODE		CONTROL BLOCK	FUNCTION
1	0	14bit TX DIVIDER	Setting Frequency for TX-VCO
0	1	14bit RX DIVIDER	Setting Frequency for RX-VCO
1	1	12bit REF DIVIDER	Setting Phase Compare Frequency
0	0	14bit OPTIONAL CONTROL	Battery Save or MUTE Control etc.

INPUT TIMING FOR SERIAL DATA

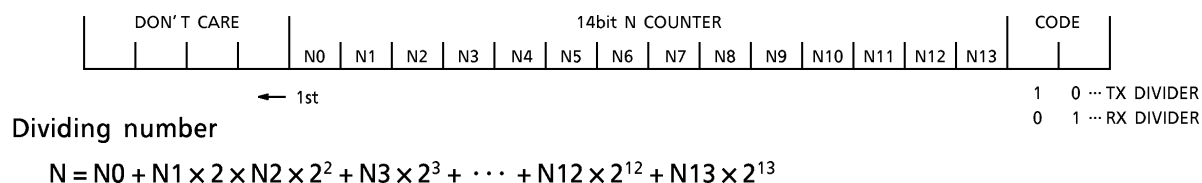
When both CLK "H" and DATA "L", STB "H" leads data active.



4. Serial data format

(1) TX DIVIDER、RX DIVIDER

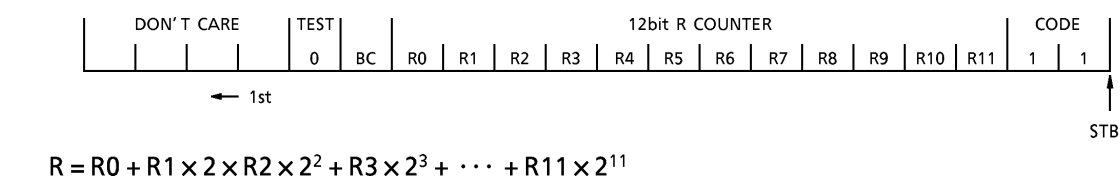
Dividing number range is 5 to 16383.



(2) REF DIVIDER

Dividing number range is 5 to 4095.

And this register includes TEST bits which must be set 0 in customer side.



BC bit is BATTERY ALARM detection setting.

③ Example of divider setting

When LOCAL OSC frequency is 10.240MHz, how to make RX-VCO oscillate some frequencies from 35.915MHz by 20kHz or 25kHz step.

① Reference frequency at PHASE DETECTOR should be set 5kHz

$$10.240\text{MHz} \div 5\text{kHz} = 2048 \quad \therefore R = 2048$$

② Calculate dividing number N for RX DIVIDER

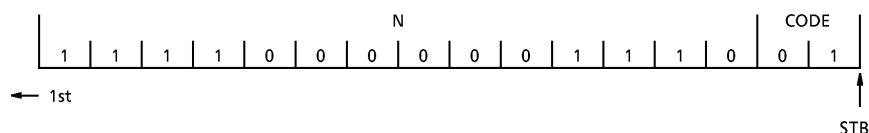
$$35.915\text{MHz} \div 5\text{kHz} = 7183 \quad \therefore N(\text{CH16}) = 7183$$

$$35.935\text{MHz} \div 5\text{kHz} = 7187 \quad \therefore N(\text{CH17}) = 7187$$

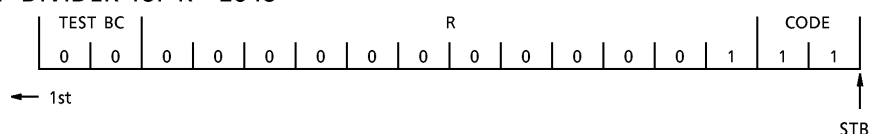
\vdots \vdots \vdots
 \vdots \vdots \vdots

③ Finally you get the following registers.

RX DIVIDER for N = 7183

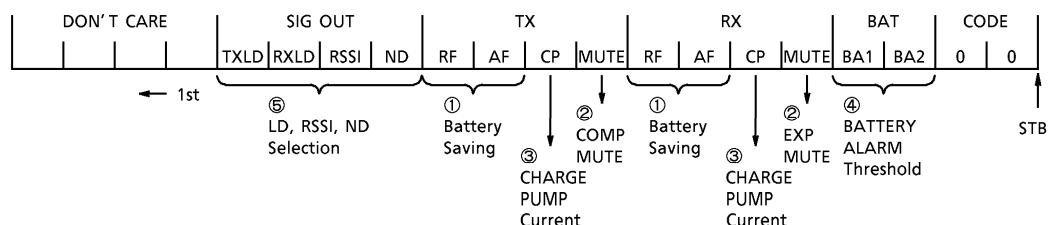


REF DIVIDER for R = 2048



(3) CONTROL

This register indicates battery saving controls for some blocks or MUTE controls for compander block or changing threshold level for BATTERY ALARM.



① Battery saving control

0 Operation 1 Battery saving

BIT	CONTROL BLOCK
TX-RF	TX-PLL
TX-AF	MIC AMP, COMPRESSOR, SPLATTER
RX-RF	RX-VCO, RX-PLL, 1st MIX, 2nd MIX, VCC2, IF AMP, NOISE DET, DATA COMP, RSSI
RX-AF	PRE AMP, EXPANDER, RECEIVER AMP

LOCAL OSC = OFF at TX-RF = 1 and RX-RF = 1

② MUTE control

0 normal 1 MUTE

TX-MUT controls MUTE for COMPRESSOR output (pin 11).

RX-MUT controls MUTE for EXPANDER output (pin 17).

These bits don't let compander block go battery saving mode, therefore current consumption doesn't decrease.

③ CHARGE PUMP current control

You can change PLL loop performance such as lock up time by these control bits.

BIT	CONTROL OUTPUT	0	1
TX-CP	TX-PLL CHARGE PUMP Output Current	200 μ A	400 μ A
RX-CP	RX-PLL CHARGE PUMP Output Current	200 μ A	400 μ A

④ BATTERY ALARM detection setting

This IC has 5 threshold levels for detection of battery dropping. These threshold levels are given by below table.

BC (*1)	BA1	BA2	V _{BAT-L}
1	1	0	2.25V
0	0	0	3.00V
0	0	1	3.25 V
0	1	0	3.30V
0	1	1	3.45 V
1	0	0	Battery (*2) Saving
1	1	1	

(*1) BC bit in REF DIVIDER.

(*2) Only for BATTERY ALARM block.

⑤ SIG OUT selection

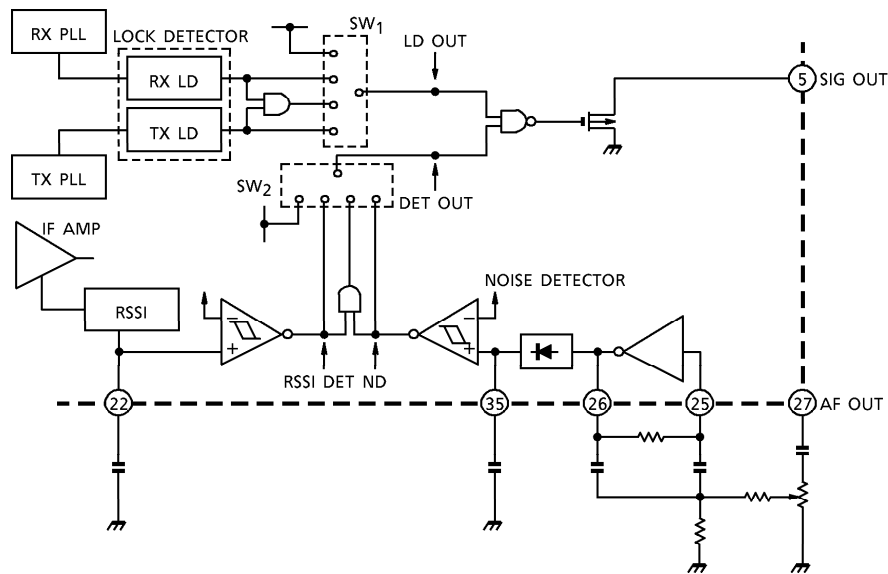


Fig.4

SIG OUT terminal (Pin 5) generates combination states of RX and TX LOCK DETECTOR, RSSI and NOISE DETECTOR as shown in Fig.4.
SW₁ and SW₂ in Fig.4 are indicated by SIG OUT selection bits in CONTROL register according to below Fig.5.

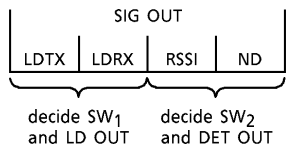


Fig.5 SIG OUT bits

EX.TX-LOCK DETECTOR Operation.

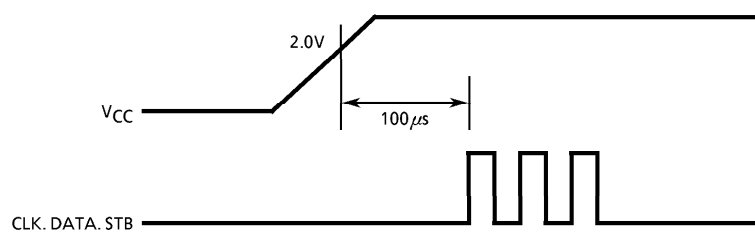
LDTX	LDRX	RSSI	ND
1	0	0	0

5. Default function

• POWER ON DATA SETTING

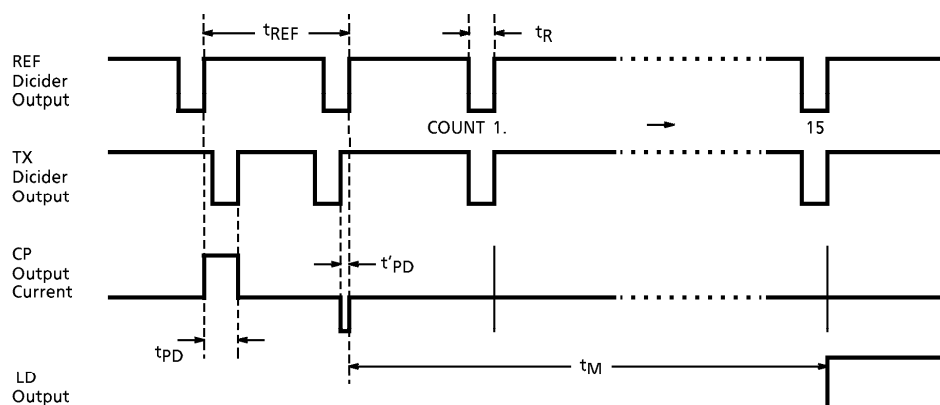
	14 bit	CODE	SETTING
REF	0 0 1 0 0 0 0 0 0 0 0 0 0 1	1 1	f = 10.240MHz
TX	1 1 1 0 1 1 1 1 0 1 1 0 0 1	1 0	f = 49.875MHz
RX	1 1 1 0 0 1 0 0 0 0 1 1 1 0	0 1	f = 36.035MHz
CONT	0 1 0 0 1 1 1 1 0 1 1 1 1 0	0 0	Stand by mode

• TIMING CHART



6. LOCK DETECTOR function

When difference of phase in to PHASE DETECTOR goes with in $2 / 10.24\text{MHz} = 195\text{ns}$ and state continues more than $15 / 5\text{kHz} = 3\text{ms}$, LOCK DETECTOR output (refer to Fig.5) changes to H state from L state.



$$t_{REF} = \frac{R}{f_{LO}} = \frac{1}{f_{REF}} = \frac{1}{5\text{kHz}} = 0.2\text{ms}$$

$$t_R = \frac{2}{f_{LO}} = 195\text{ns}, \quad t_M = 3\text{ms} \quad \text{at } f_{LO} = 10.24\text{MHz}$$

$$t'_{PD} < t_R = 195\text{ns}$$

(Note) When STB input goes H state in TX DIVIDER mode (code1, 0), LOCK DETECTOR always outputs L level. Therefore you should care that you might take as unlock state in correctly. If the same number in TX DIVIDER would be inputted.

7. NOISE DETECTOR

(1) NOISE FILTER AMP

NOISE FILTER AMP can construct band pass filter as Fig.6 Center frequency f_0 in BPF should be set around 30kHz because of pre stage LPF and post stage HPF.

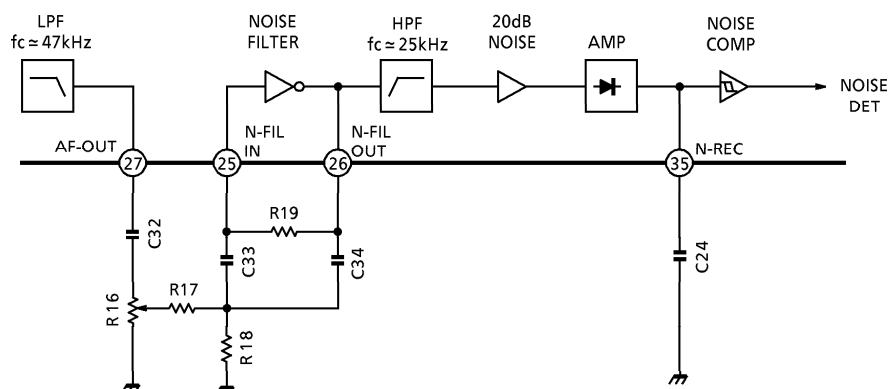


Fig.6

BPF FORMULA

$$f_0 = \frac{1}{2\pi\sqrt{R19(R17//R18)}C^2} \quad \dots\dots (1)$$

$$G_V = R19 / 2 R17 \quad \dots\dots (2)$$

$$Q^2 = \frac{R19}{4(R17//R18)} \quad \dots\dots (3)$$

at $C33 = C34 = C$, $R17 \gg R16$

SETTING EXAMPLE

$R16 = 20k\Omega$ (VR), $R17 = 330k\Omega$

$R18 = 3.3k\Omega$, $R19 = 150k\Omega$

$C = 220pF$

(1), (2), (3) provide below

$f_0 \approx 31kHz$, $G_V \approx -13dB$

$Q^2 \approx 12$

(Note) Please separate lines of pin 25 and pin 27 as far as possible in desiring layout. NOISE DETECTOR in this IC is so high sensitive that it might be easy to detect incorrectly by layout.

(2) NOISE COMPARATOR

When the direct voltage at pin 35 drops under 0.4V, NOISE COMP outputs L level at point ND in Fig.4. NOISE COMP has around 100mV hysteresis at pin 35.

Rising time in NOISE DETECTOR is in direct proportion to time constant 7.5ms of $C24 = 0.1\mu F$ and internal 75k Ω . Decreasing the value of C24 makes the response faster but might increase misdetection by vibration at pin 35.

8. RSSI

(1) RSSI function

A DC voltage corresponding to the input level of IF input pins (pin 32) is output to the RSSI (Pin22). While the linear range is about 70dB when $V_{CC}=3.6V$, the range can be expanded to 80dB as in Fig.7.

However, in such a case, note that the temperature characteristics of the RSSI output may alter due to a disparity between the temperature coefficient of the external resistor and the internal resistance of the IC.

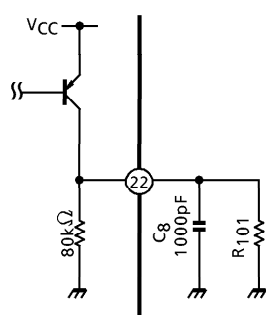
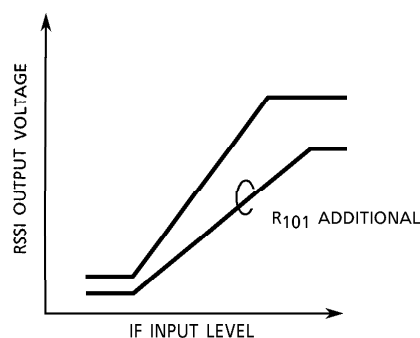


Fig.7



(2) RSSI COMPARATOR

The result of RSSI COMPARATOR is output by comparing output voltage of RSSI terminal with around 0.8V.

Hysteresis range is about 65mV.

When $0.8V < \text{RSSI voltage}$, RSSI COMPARATOR is "L" level.

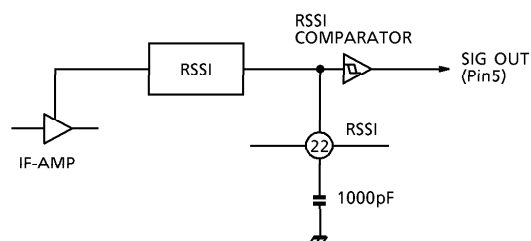


Fig.8

9. 1st MIX

Produces 1st IF signal (10.695MHz) by mixing RF signal with RX-VCO signal. Fig.9 shows input matching for 1st MIX IN (pin 40). Input matching gain is around 15dB.

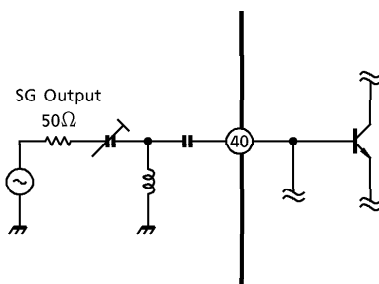


Fig.9

10. IF detector

1st IF is transformed to 2nd IF signal (455 or 450kHz) in 2nd MIX by mixing LOCAL OSC signal which also provides PLL reference frequency. Output impedance in 2nd MIX OUT (pin 34) is adjusted to that of standard ceramic filter, therefore you can reduce matching resistor. Operating frequency of 2nd MIX is restricted to around 30MHz because of preventing interference for other block. IF AMP has about 75dB gain. IF IN (pin 32) is also matched to ceramic filter impedance (1.8kΩ).

Quadrature detection with external discriminator demodulates audio signal from AF OUT (pin 27). Both ceramic and coil are useful as discriminator. We chose ceramic discriminator in main application diagram and measurement circuit but when you use coil, the connection in Fig.10 is recommended.

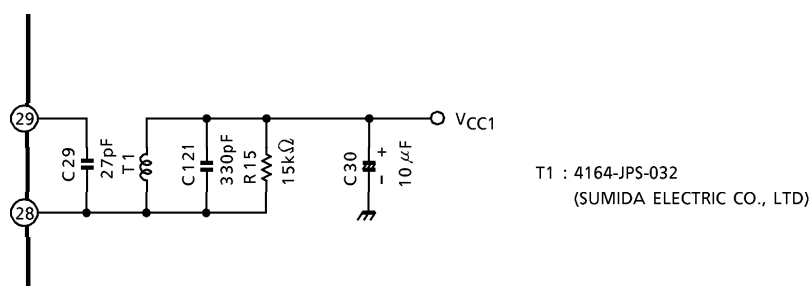


Fig.10

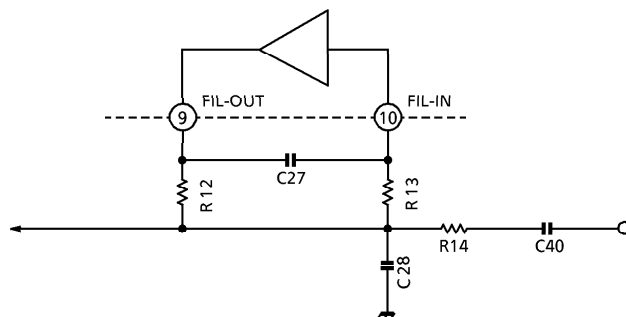
Damping resistor R15 decides audio output level V_{OD} . You can boost V_{OD} by increasing the value of R15, but at that time temperature slope of V_{OD} level has increased. Center frequency f_0 and V_{OD} also depend on C29 and discriminator. Good temperature character should be required as C29. Especially in case of coil used. C121 is required good temperature character as well.

DISCRIMINATER		
	Ceramic CDBM455C24	Coil at Fig.10
V_{OD} level	220mV _{rms}	190mV _{rms}

(Typ.)

AF OUT (pin 27) includes 3 stage low pass filter with cut off frequency $f_c \approx 47\text{kHz}$ to reduce output carrier leak which quadrature mixing produces.

11. SPLATTER FILTER AMP adjustment



$$(1) \quad f_0 = \frac{1}{2\pi\sqrt{C28 \cdot C27 \cdot R12 \cdot R14}}$$

$$(2) \quad Q = \frac{1}{3} \sqrt{\frac{C28}{C27}}$$

$$(3) \quad G_V = 20 \log \frac{R12}{R14} = 0$$

at $R12 = R13 = R14$

• EXAMPLE

$R12 = R13 = R14 = 39\text{k}\Omega$, $C27 = 430\text{pF}$, $C28 = 3900\text{pF}$

$$(1) \quad f_0 = 3.14\text{kHz}$$

$$(2) \quad Q = 1.0$$

$$(3) \quad G_V = 0$$